

The GreenMOS® high voltage MOSFET utilizes charge balance technology to achieve outstanding low on-resistance and lower gate charge. It is engineered to minimize conduction loss, provide superior switching performance and robust avalanche capability.

The GreenMOS® Generic series is optimized for extreme switching performance to minimize switching loss. It is tailored for high power density applications to meet the highest efficiency standards.



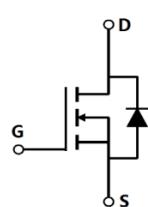
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| Parameter                               | Value | Unit |
|---|-------|------|
| $V_{DS, \min}$ @ $T_{j(\max)}$          | 850   | V    |
| $I_D, \text{pulse}$                     | 15    | A    |
| $R_{DS(ON)}, \text{max}$ @ $V_{GS}=10V$ | 900   |      |
| $Q_g$                                   | 11.7  | nC   |

| Product Name | Package | Marking    |
|--------------|---------|------------|
| OSG80R900FF  | TO220F  | OSG80R900F |



**Absolute Maximum Ratings** at  $T_j=25^\circ\text{C}$  unless otherwise noted

| Parameter  | Symbol   | Value    | Unit |
|--|----------|----------|------|
| Drain-source voltage   | $V_{DS}$ | 800      | V    |
| Gate-source voltage  | $V_{GS}$ | $\pm 30$ | V    |
| Continuous drain current <sup>1)</sup> , $T_C=25^\circ\text{C}$  | $I_D$    | 5        | A    |
| Continuous drain current <sup>1)</sup> , $T_C=100^\circ\text{C}$ |          | 3.2      |      |

 Pulsed drain current<sup>2)</sup>, T

**Dynamic Characteristics**

| Parameter                    | Symbol              | Min. | Typ. | Max. | Unit | Test condition   |
|------------------------------|---------------------|------|------|------|------|--|
| Input capacitance            | C <sub>iss</sub>    |      |      |      | pF   | V <sub>GS</sub> =0 V,<br>V <sub>DS</sub> =50 V,<br>00 kHz                                  |
| Output capacitance           | C <sub>oss</sub>    |      | 36.1 |      | pF   |  |
| Reverse transfer capacitance | C <sub>rss</sub>    |      | 1.5  |      | pF   |  |
| Turn-on delay time           | t <sub>d(on)</sub>  |      | 31.3 |      | ns   | V <sub>GS</sub> =10 V,<br>V <sub>DS</sub> =400 V,<br>R <sub>G</sub><br>I <sub>D</sub> =4 A |
| Rise time                    | t <sub>r</sub>      |      | 16.4 |      | ns   |  |
| Turn-off delay time          | t <sub>d(off)</sub> |      | 54.6 |      | ns   |  |
| Fall time                    | t <sub>f</sub>      |      | 7.0  |      | ns   |  |

**Gate Charge Characteristics**

| Parameter | Symbol | Min. | Typ. | Max. | Unit | Test condition |
|-----------|--------|------|------|------|------|----------------|
|-----------|--------|------|------|------|------|----------------|

## Electrical Characteristics Diagrams

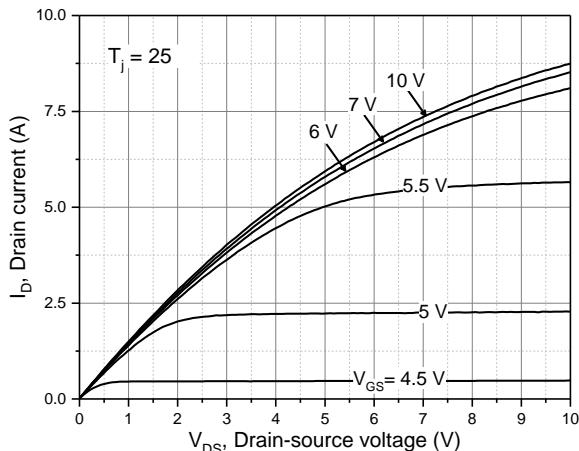


Figure 1. Typ. output characteristics

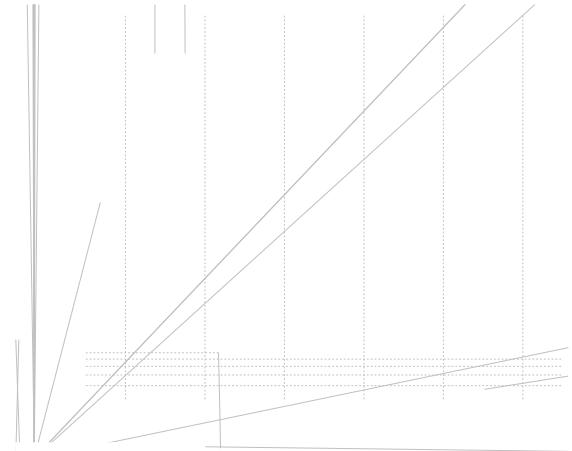


Figure 2. Typ. transfer characteristics

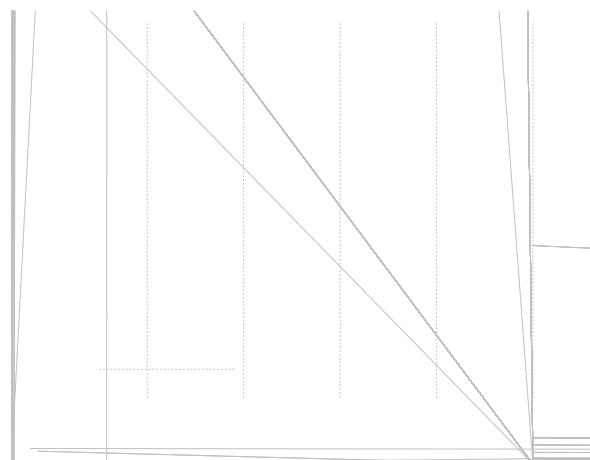


Figure 3. Typ. capacitances

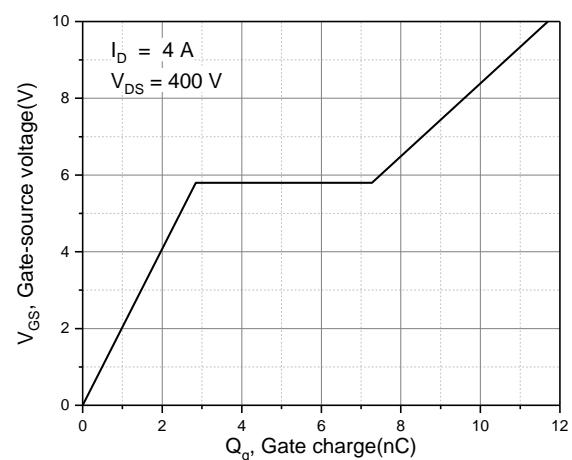


Figure 4. Typ. gate charge

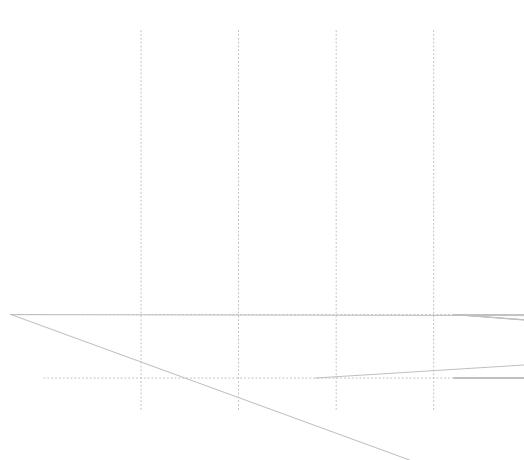


Figure 5. Drain-source breakdown voltage

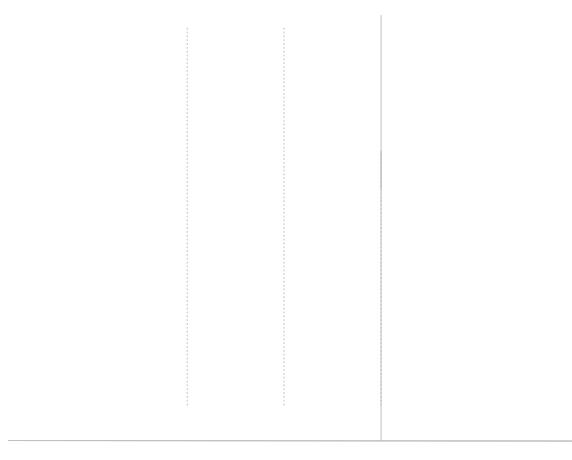
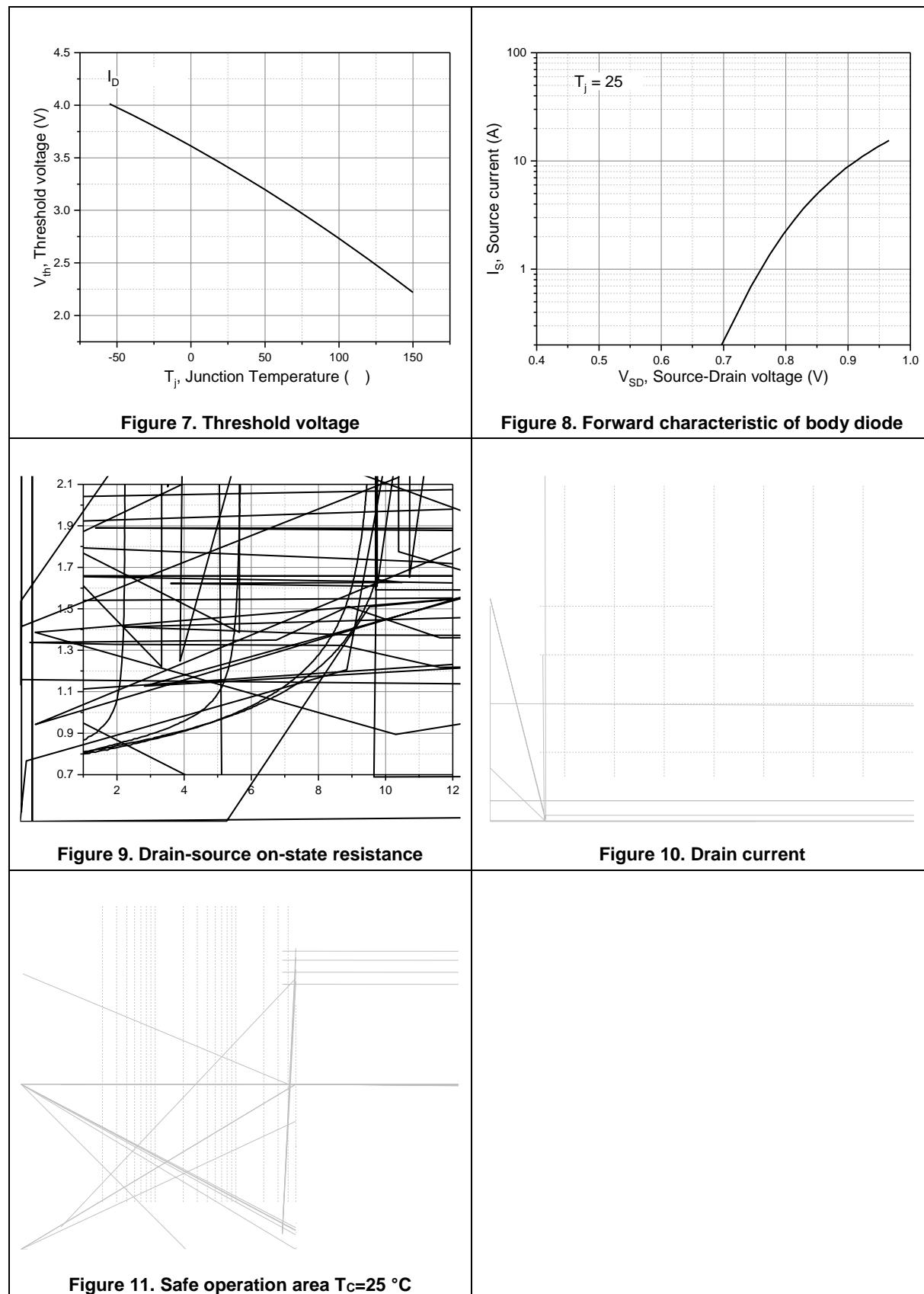
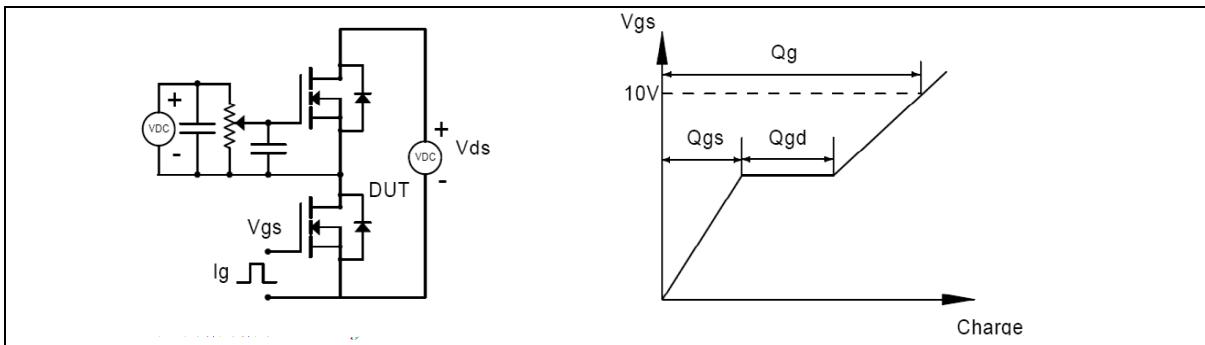


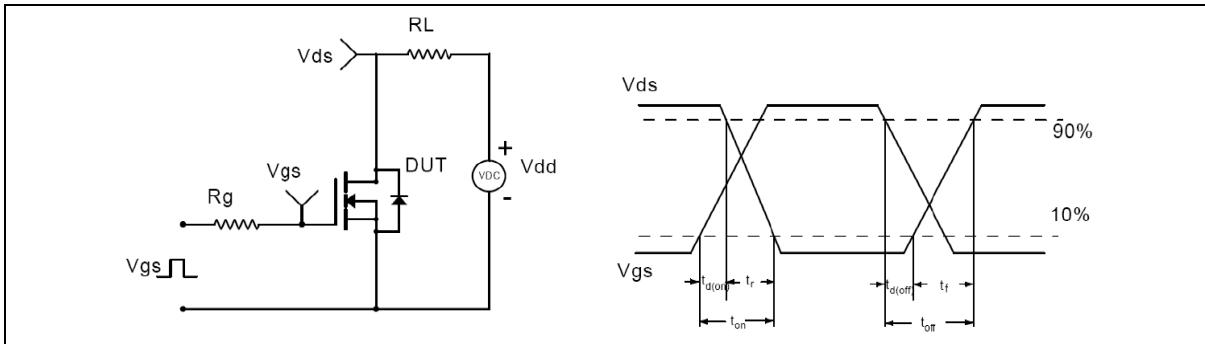
Figure 6. Drain-source on-state resistance



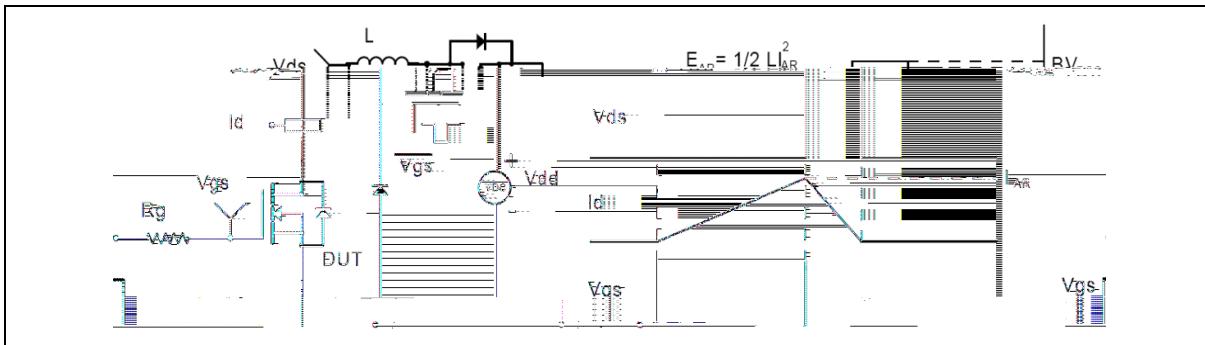
### Test circuits and waveforms



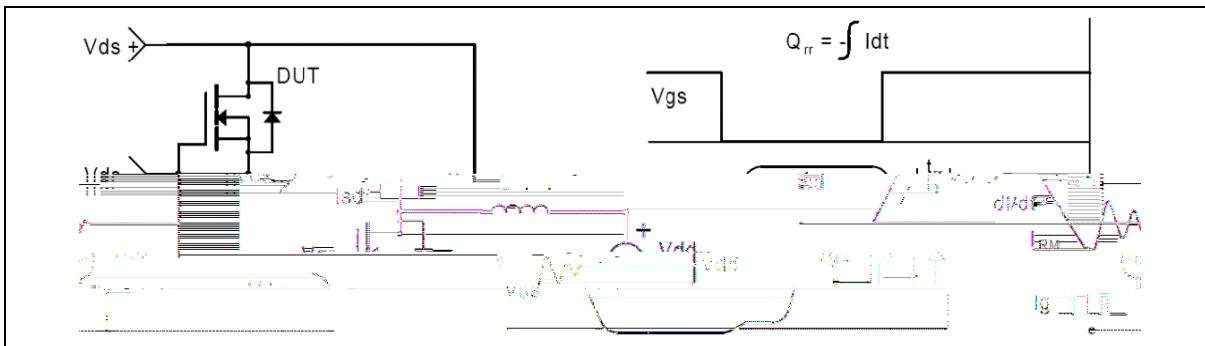
**Figure 1. Gate charge test circuit & waveform**



**Figure 2. Switching time test circuit & waveforms**



**Figure 3. Unclamped inductive switching (UIS) test circuit & waveforms**



**Figure 4. Diode reverse recovery test circuit & waveforms**

## Package Information

| mm      |       |       |
|---------|-------|-------|
| Min     | Nom   | Max   |
| 9.96    | 10.16 | 10.36 |
| 4.50    | 4.70  | 4.90  |
| 2.34    | 2.54  | 2.74  |
| 2.56    | 2.76  | 2.96  |
| 0.40    | 0.50  | 0.65  |
| 5.57    | 15.87 | 16.17 |
| 6.70REF |       |       |
| 2.54BSC |       |       |
| 2.68    | 12.98 | 13.28 |

## Ordering Information

| Package Type | Units/Tube | Tubes/Inner Box | Units/Inner Box | Inner Boxes/Carton Box | Units/Carton Box |
|--------------|------------|-----------------|-----------------|------------------------|------------------|
| TO220F-C     | 50         | 20              | 1000            | 6                      | 6000             |

## Product Information

| Product     | Package | Pb Free | RoHS | Halogen Free |
|-------------|---------|---------|------|--------------|
| OSG80R900FF | TO220F  | yes     | yes  | yes          |

